

74VHCV240FT, 74VHCV244FT

1. Functional Description

- Octal Schmitt Bus Buffer
- 74VHCV240FT: Inverted, 3-State Outputs
- 74VHCV244FT: Non-Inverted, 3-State Outputs

2. General

The 74VHCV240FT and 74VHCV244FT are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHCV240FT is an inverting 3-state buffer having two active-low output enables. The 74VHCV244FT is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

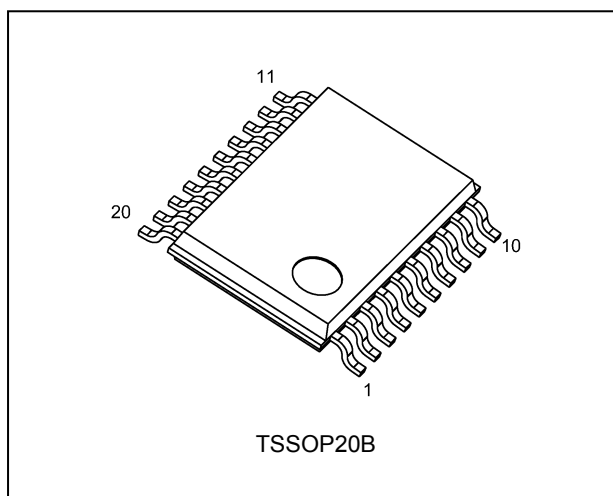
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 3.9$ ns (typ.) at $V_{CC} = 5.0$ V
- (4) Low power dissipation: $I_{CC} = 2.0$ μ A (max) at $T_a = 25$ °C
- (5) Wide operating voltage range: $V_{CC(opr)} = 1.8$ V to 5.5 V
- (6) Output current: $|I_{OH}|/I_{OL} = 16$ mA (min) ($V_{CC} = 4.5$ V)
- (7) Power-down protection provided on all inputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 240 or 244 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

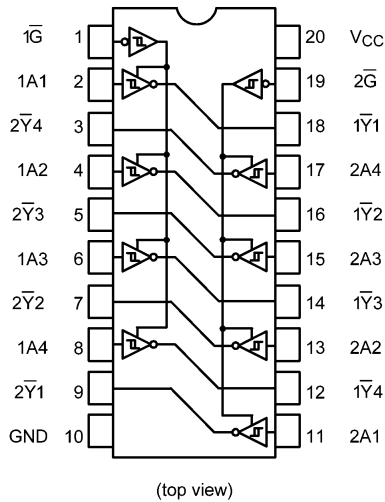
4. Packaging



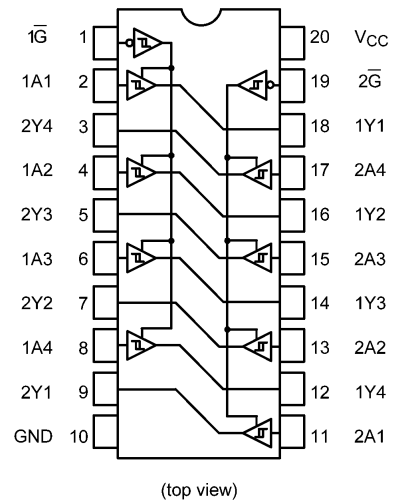
Start of commercial production
2014-07

5. Pin Assignment

74VHCV240FT

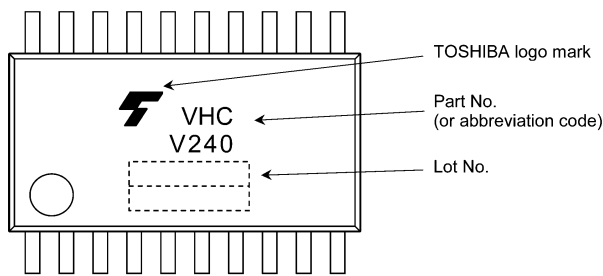


74VHCV244FT

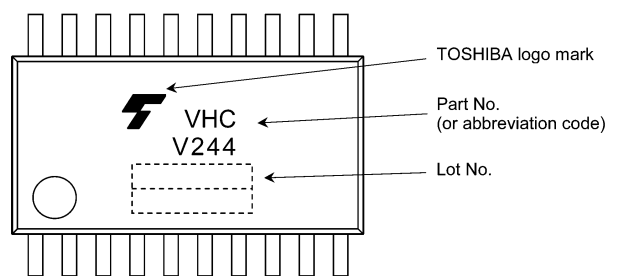


6. Marking

74VHCV240FT



74VHCV244FT



7. Truth Table

Input \bar{G}	Input A_n	Output Y_n	Output \bar{Y}_n
L	L	L	H
L	H	H	L
H	X	Z	Z

- X: Don't care
- Z: High impedance
- Y_n : 74VHCV244FT
- \bar{Y}_n : 74VHCV240FT

8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to 7.0	V
Output voltage	V_{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to $V_{CC} + 0.5$	
Input diode current	I_{IK}		-50	mA
Output diode current	I_{OK}	(Note 3)	± 50	mA
Output current	I_{OUT}		± 50	mA
Power dissipation	P_D	(Note 4)	180	mW
V_{CC} /ground current	I_{CC}		± 100	mA
Storage temperature	T_{stg}		-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Note 4: 180 mW in the range of $T_a = -40$ to $85^{\circ}C$. From $T_a = 85$ to $125^{\circ}C$ a derating factor of -3.25 mW/ $^{\circ}C$ shall be applied until 50 mW.

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V_{CC}		—	1.8 to 5.5	V
Input voltage	V_{IN}		—	0 to 5.5	V
Output voltage	V_{OUT}	(Note 1)	—	0 to 5.5	V
		(Note 2)	—	0 to V_{CC}	
Operating temperature	T_{opr}		—	-40 to 125	$^{\circ}C$
Input rise and fall times	dt/dv		$V_{CC} = 3.3 \pm 0.3$ V	0 to 20	ms/V
			$V_{CC} = 5.0 \pm 0.5$ V	0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Typ.	Max	Unit	
Positive threshold voltage	V_P	—	1.8	—	—	1.65	V	
			2.3	—	—	1.85		
			3.0	—	—	2.20		
			4.5	—	—	3.15		
			5.5	—	—	3.85		
Negative threshold voltage	V_N	—	1.8	0.15	—	—	V	
			2.3	0.45	—	—		
			3.0	0.90	—	—		
			4.5	1.35	—	—		
			5.5	1.65	—	—		
Hysteresis voltage	V_H	—	1.8	0.15	—	1.05	V	
			2.3	0.20	—	1.10		
			3.0	0.30	—	1.20		
			4.5	0.40	—	1.40		
			5.5	0.50	—	1.60		
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\text{ }\mu\text{A}$	1.8	1.7	1.8	—	V
			$I_{OH} = -8\text{ mA}$	3.0	2.9	3.0	—	
			$I_{OH} = -16\text{ mA}$	4.5	4.4	4.5	—	
				4.5	3.94	—	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50\text{ }\mu\text{A}$	1.8	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			$I_{OL} = 8\text{ mA}$	3.0	—	—	0.36	
			$I_{OL} = 16\text{ mA}$	4.5	—	—	0.44	
3-state output OFF-state leakage current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 5.5 V	1.8 to 5.5	—	—	± 0.5	μA	
Power-OFF leakage current	I_{OFF}	$V_{IN}/V_{OUT} = 5.5\text{ V}$	0	—	—	0.5	μA	
Input leakage current	I_{IN}	$V_{IN} = 5.5\text{ V}$ or GND	0 to 5.5	—	—	± 0.1	μA	
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	2.0	μA	

10.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit	
Positive threshold voltage	V_P	—	1.8	—	1.65	V	
			2.3	—	1.85		
			3.0	—	2.20		
			4.5	—	3.15		
			5.5	—	3.85		
Negative threshold voltage	V_N	—	1.8	0.15	—	V	
			2.3	0.45	—		
			3.0	0.90	—		
			4.5	1.35	—		
			5.5	1.65	—		
Hysteresis voltage	V_H	—	1.8	0.15	1.05	V	
			2.3	0.20	1.10		
			3.0	0.30	1.20		
			4.5	0.40	1.40		
			5.5	0.50	1.60		
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50 \mu A$	1.8	1.7	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			$I_{OH} = -8 \text{ mA}$	3.0	2.48	—	
				4.5	3.80	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50 \mu A$	1.8	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			$I_{OL} = 8 \text{ mA}$	3.0	—	0.44	
				4.5	—	0.55	
3-state output OFF-state leakage current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 5.5 V	1.8 to 5.5	—	± 5.0	μA	
Power-OFF leakage current	I_{OFF}	$V_{IN}/V_{OUT} = 5.5 \text{ V}$	0	—	5.0	μA	
Input leakage current	I_{IN}	$V_{IN} = 5.5 \text{ V}$ or GND	0 to 5.5	—	± 1.0	μA	
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	20.0	μA	

10.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit		
Positive threshold voltage	V_P	—	1.8	—	1.65	V		
			2.3	—	1.85			
			3.0	—	2.20			
			4.5	—	3.15			
			5.5	—	3.85			
Negative threshold voltage	V_N	—	1.8	0.15	—	V		
			2.3	0.45	—			
			3.0	0.90	—			
			4.5	1.35	—			
			5.5	1.65	—			
Hysteresis voltage	V_H	—	1.8	0.15	1.05	V		
			2.3	0.20	1.10			
			3.0	0.30	1.20			
			4.5	0.40	1.40			
			5.5	0.50	1.60			
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50 \mu A$	1.8	1.7	—	V	
				3.0	2.9	—		
			$I_{OH} = -8 mA$	4.5	4.4	—		
				$I_{OH} = -16 mA$	3.0	2.40		—
					4.5	3.70		—
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50 \mu A$	1.8	—	0.1	V	
				3.0	—	0.1		
				4.5	—	0.1		
			$I_{OL} = 8 mA$	3.0	—	0.55		
				$I_{OL} = 16 mA$	4.5	—		0.65
3-state output OFF-state leakage current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to $5.5 V$	1.8 to 5.5	—	± 20.0	μA		
Power-OFF leakage current	I_{OFF}	$V_{IN}/V_{OUT} = 5.5 V$	0	—	20.0	μA		
Input leakage current	I_{IN}	$V_{IN} = 5.5 V$ or GND	0 to 5.5	—	± 2.0	μA		
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	40.0	μA		

10.4. AC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$, Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Part Number	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Unit
Propagation delay time	74VHCV240FT	t_{PLH}, t_{PHL}		—	2.5 ± 0.2	15	—	6.4	11.6	ns
						50	—	9.2	14.4	
					3.3 ± 0.3	15	—	5.0	7.5	
						50	—	7.0	11.0	
					5.0 ± 0.5	15	—	3.9	5.5	
						50	—	5.4	7.5	
Propagation delay time	74VHCV244FT	t_{PLH}, t_{PHL}		—	2.5 ± 0.2	15	—	6.7	12.5	ns
						50	—	9.5	15.3	
					3.3 ± 0.3	15	—	5.0	8.4	
						50	—	7.2	11.9	
					5.0 ± 0.5	15	—	3.8	5.5	
						50	—	5.4	7.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1\text{ k}\Omega$	2.5 ± 0.2	15	—	7.8	14.6	ns
						50	—	11.1	17.8	
					3.3 ± 0.3	15	—	5.7	10.6	
						50	—	8.4	14.1	
					5.0 ± 0.5	15	—	4.1	7.3	
						50	—	6.2	9.3	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1\text{ k}\Omega$	2.5 ± 0.2	50	—	14.3	19.2	ns
					3.3 ± 0.3	50	—	10.9	14.0	
					5.0 ± 0.5	50	—	8.7	9.2	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	—	2.5 ± 0.2	50	—	—	2.0	ns
					3.3 ± 0.3	50	—	—	1.5	
					5.0 ± 0.5	50	—	—	1.0	
Input capacitance		C_{IN}		—			—	4	10	pF
Output capacitance		C_{OUT}		—			—	6	—	pF
Power dissipation capacitance	74VHCV240FT	C_{PD}	(Note 2)	—			—	20	—	pF
	74VHCV244FT	C_{PD}	(Note 2)	—			—	21	—	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLHM} - t_{PLHN}|$, $t_{osHL} = |t_{PHLM} - t_{PHLN}|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8 \text{ (per bit)}$$

10.5. AC Characteristics
 (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit
Propagation delay time	74VHCV240FT	t_{PLH}, t_{PHL}		—	2.5 ± 0.2	15	1.0	14.0	ns
						50	1.0	17.0	
					3.3 ± 0.3	15	1.0	9.0	
						50	1.0	12.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	74VHCV244FT	t_{PLH}, t_{PHL}		—	2.5 ± 0.2	15	1.0	15.0	ns
						50	1.0	18.0	
					3.3 ± 0.3	15	1.0	10.0	
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1\text{ k}\Omega$	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	21.0	
					3.3 ± 0.3	15	1.0	12.5	
						50	1.0	16.0	
					5.0 ± 0.5	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1\text{ k}\Omega$	2.5 ± 0.2	50	1.0	21.0	ns
					3.3 ± 0.3	50	1.0	16.0	
					5.0 ± 0.5	50	1.0	10.5	
Output skew		$t_{oS LH}, t_{oS HL}$	(Note 1)	—	2.5 ± 0.2	50	—	2.0	ns
					3.3 ± 0.3	50	—	1.5	
					5.0 ± 0.5	50	—	1.0	
Input capacitance		C_{IN}		—			—	10	pF

Note 1: Parameter guaranteed by design. ($t_{oS LH} = |t_{PLHm} - t_{PLHn}|$, $t_{oS HL} = |t_{PHLm} - t_{PHLn}|$)

10.6. AC Characteristics
(Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit						
Propagation delay time	74VHCV240FT	t_{PLH}, t_{PHL}		—	2.5 ± 0.2	15	1.0	16.0	ns						
						50	1.0	19.0							
					3.3 ± 0.3	15	1.0	10.5							
						50	1.0	14.0							
					5.0 ± 0.5	15	1.0	7.5							
						50	1.0	9.5							
					Propagation delay time	74VHCV244FT	t_{PLH}, t_{PHL}			—	2.5 ± 0.2	15	1.0	17.0	ns
												50	1.0	20.0	
3.3 ± 0.3	15	1.0	11.5												
	50	1.0	15.0												
5.0 ± 0.5	15	1.0	7.5												
	50	1.0	9.5												
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1$ k Ω					2.5 ± 0.2		15	1.0	19.0	ns	
											50	1.0	23.5		
					3.3 ± 0.3	15	1.0	14.5							
						50	1.0	18.0							
					5.0 ± 0.5	15	1.0	10.0							
						50	1.0	12.0							
					3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1$ k Ω	2.5 ± 0.2	50	1.0	22.5		ns
										3.3 ± 0.3	50	1.0	17.5		
5.0 ± 0.5	50	1.0	11.5												
Output skew		$t_{oS LH}, t_{oS HL}$	(Note 1)	—	2.5 ± 0.2	50	—	2.0	ns						
					3.3 ± 0.3	50	—	1.5							
					5.0 ± 0.5	50	—	1.0							
Input capacitance		C_{IN}		—			—	10	pF						

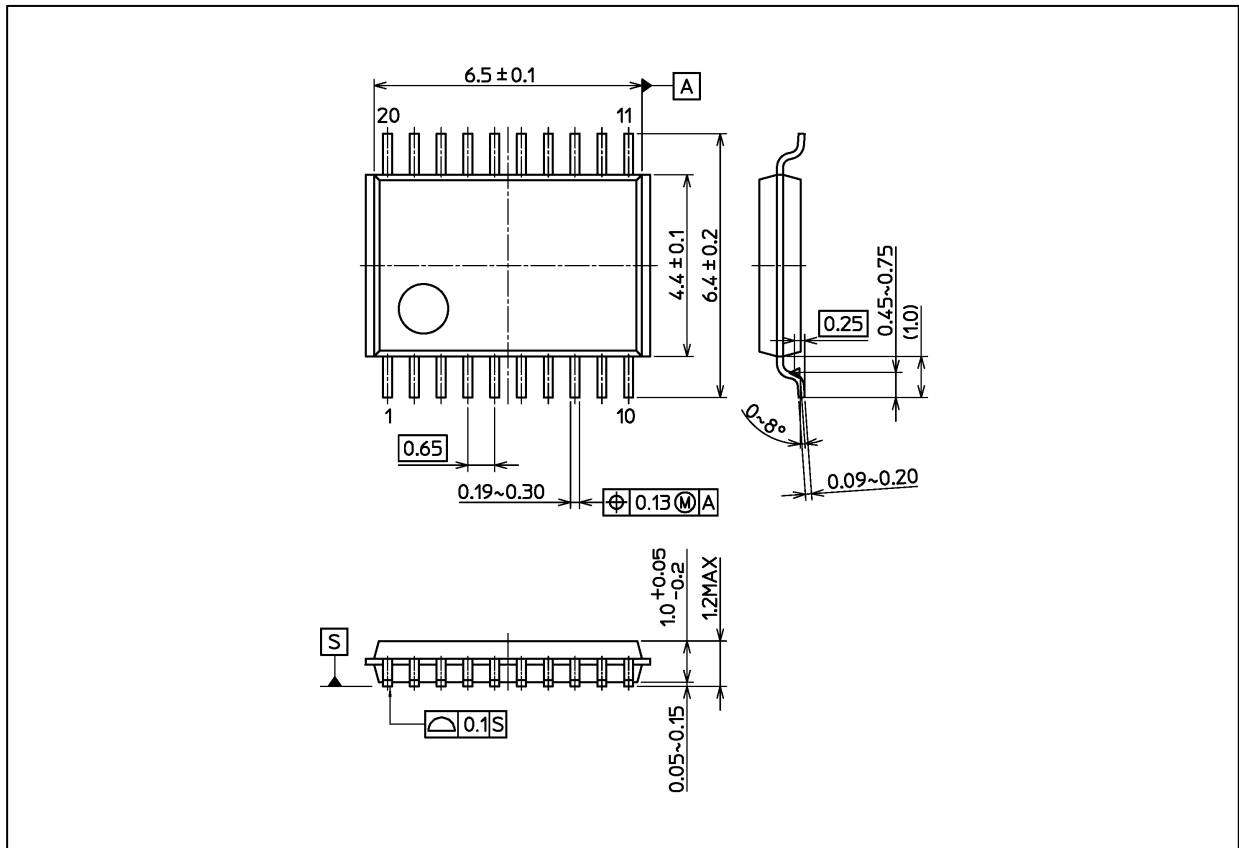
Note 1: Parameter guaranteed by design. ($t_{oS LH} = |t_{PLHM} - t_{PLHN}|$, $t_{oS HL} = |t_{PHLM} - t_{PHLN}|$)

10.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Typ.	Limit	Unit
Quiet output maximum dynamic V_{OL}	V_{OLP}	$C_L = 50$ pF	3.3	0.45	—	V
			5.0	0.9	—	
Quiet output minimum dynamic V_{OL}	V_{OLV}	$C_L = 50$ pF	3.3	-0.1	—	V
			5.0	-0.3	—	
Minimum high-level dynamic input voltage	V_{IHD}	$C_L = 50$ pF	5.0	—	3.5	V
Maximum low-level dynamic input voltage	V_{ILD}	$C_L = 50$ pF	5.0	—	1.5	V

Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

Package Name(s)
Nickname: TSSOP20B

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